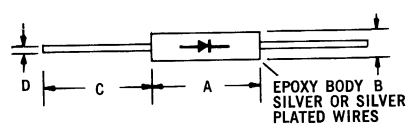


HIGH VOLTAGE DIFFUSED SILICON POWER RECTIFIERS

SERIES VF



VARO Type No. Average Forward Current, @ T _A = 40°C, I _O			Peak Repetitive Reverse Voltage, V _{RRM} (Volts)	Max. Inst. Forward Voltage Drop @ T _A = 25°C and I _O V _{FM} (Volts)	Case Style
5mA	10mA	25mA			
VF5- 5	VF10- 5	VF25- 5	5,000	12	A
VF5- 7	VF10- 7	VF25- 7	7,000	12	A
VF5-10	VF10-10	VF25-10	10,000	18	A
VF5-12	VF10-12	VF25-12	12,000	18	A
VF5-15	VF10-15	VF25-15	15,000	35	B
VF5-20	VF10-20	VF25-20	20,000	35	B
VF5-25	VF10-25	VF25-25	25,000	35	B
VF5-30	VF10-30	VF25-30	30,000	50	C
VF5-40	VF10-40	VF25-40	40,000	50	C
VF5- 5X	VF10- 5X	VF25- 5X	5,000	15	A
VF5- 7X	VF10- 7X	VF25- 7X	7,000	15	A
VF5-10X	VF10-10X	VF25-10X	10,000	30	A
VF5-12X	VF10-12X	VF25-12X	12,000	30	A
VF5-15X	VF10-15X	VF25-15X	15,000	60	B
VF5-20X	VF10-20X	VF25-20X	20,000	60	B
VF5-25X	VF10-25X	VF25-25X	25,000	60	B
VF5-30X	VF10-30X	VF25-30X	30,000	90	C
VF5-40X	VF10-40X	VF25-40X	40,000	90	C

ELECTRICAL CHARACTERISTICS AT T = 25°C (UNLESS OTHERWISE SPECIFIED)	
Max. DC Reverse Current @ Rated V _{RRM} and 25°C, I _{RM}	1μA
Max. DC Reverse Current @ Rated V _{RRM} and $\frac{100^{\circ}\text{C}}{85^{\circ}\text{C}}$, I _{RM}	$\frac{20\mu\text{A}}{30\mu\text{A}^*}$
Max. Reverse Recovery Time @ I _F = 2mA and I _R = 4mA, Recovery to 1.0mA, t _{rr}	250 nanosec*
Ambient Operating Temperature Range, T _A	-55°C to $\frac{+150^{\circ}\text{C}}{+85^{\circ}\text{C}^*}$
Storage Temperature Range, T _{STG}	-55°C to +150°C
Max. One-Half Cycle Surge Current @ 60 Hz, I _{FSM}	3 Amps

*Fast Recovery Series